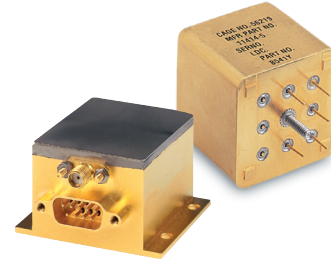


# 9600

## Ultra-miniature Space and Military OCXO Series



### Key Features

- Output Frequency: 4 MHz - 60 MHz
- Warm-Up Time:  $\leq 5$  minutes from 25°C
- Fast Warm-Up Option Available
- Low Power Consumption:  $< 1.3W$  @ 25°C (In Vacuum)
- Compact Sizes - Typical: 1.33" x 1.33" x 1.33"
- Frequency Aging:  
 5 MHz:  $< 5.0E-11$ /day  
 10 MHz:  $< 3.0E-10$ /day
- Frequency Change vs. Temperature:  $\pm 4.0E-9$  [-40°C to +65°C]
- Low g-sensitivity Option Available

### Options

Available options for this product include:

- Output frequency (4 MHz to 60 MHz available)
- Output format (Sine wave, TTL, or LVDS)
- Panel-mount or PCB-mount package style
- Component screening to space (grade 1) requirements
- Fast warm-up time:  $\leq 5$  minutes to within  $2.0E-8$  of final frequency from -40°C (+25°C is standard). Warm-up power increases to approx. 14 W.
- Low acceleration sensitivity of  $\leq 2.0E-10$  at 10 MHz
- Crystal radiation preconditioning

Contact Microsemi® to configure a 9600-series oscillator that will meet your specific needs.

Microsemi's 9600 is an ultra-miniature ovenized crystal oscillator designed to provide a high stability output for a wide variety of military and space applications.

The use of hybrid circuitry allows for the greatest possible reduction in size without compromises in performance or reliability.

Assembly is performed by skilled operators certified to NASA approved workmanship standards. Hybrid circuits are produced at facilities qualified to MIL-PRF-38534C. All discrete components are manufactured and tested standard to grade 2 or optionally to grade 1 requirements per MIL-STD-975.

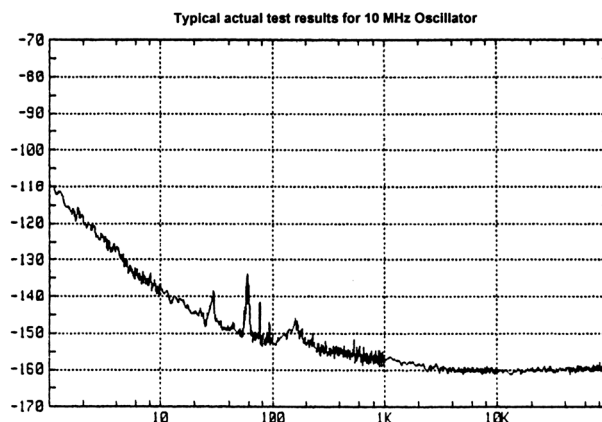
The rugged 9600 features a SC-cut quartz resonator and sustaining electronics that are controlled at a precise temperature to achieve temperature-insensitive performance, and excellent short term stability, phase noise, and aging

characteristics. This allows it to meet the challenges of many military and space specifications for time and frequency, even under the most adverse environmental conditions.

Backed by an extensive oscillator legacy, the 9600 series can be customized in output frequency, warm-up time, g-sensitivity, and other characteristics, making it useful for applications such as:

- Radio navigation
- Radar warning receivers
- Satellite transmission
- Satellite tracking and guidance

This rugged, compact crystal oscillator is especially advantageous when utilized in mobile transportable and portable applications where fast warm-up, low power consumption and small size are required.



Typical phase noise test results for the 10MHz oscillator

## 9600 SPECIFICATIONS

### ELECTRICAL SPECIFICATIONS

	5 MHz	10 MHz
Standard Output Frequency	5 MHz	10 MHz
Initial Accuracy	±5.0E-8	±5.0E-8
Format	Sine wave	Sine wave
	[TTL or LVDS optional]	[TTL or LVDS optional]
Amplitude	7.0 dBm ±1 dB	7.0 dBm ±1 dB
Harmonic distortion	<-30 dBc	<-30 dBc
Non-harmonic distortion	<-90 dBc	<-90 dBc
Load impedance	50 Ω	50 Ω
VSWR	1.5:1	1.5:1

### PERFORMANCE PARAMETERS

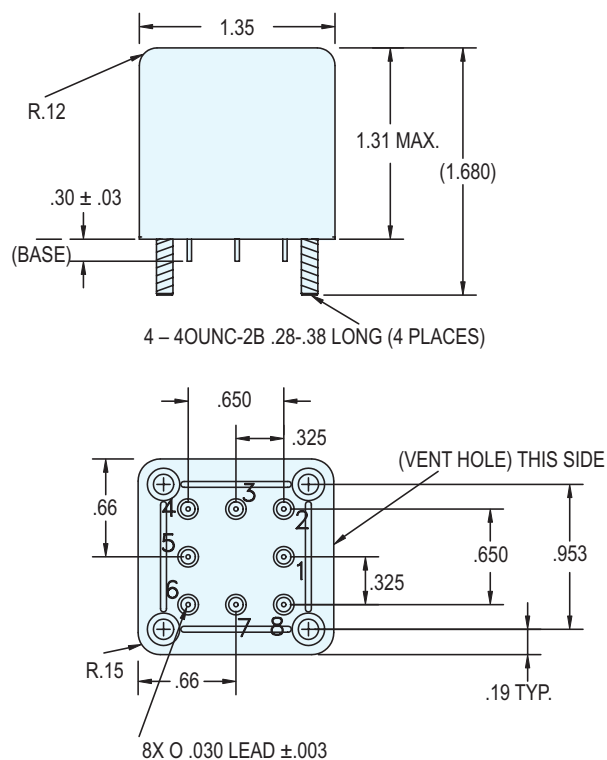
Short-term stability		
1 second (Allan deviation):	<2.0E-12	<5.0E-12
10 second (Allan deviation):	<2.0E-12	<5.0E-12
100 second (Allan deviation):	<5.0E-12	<1.0E-11
SSB phase noise (static)		
1 Hz	-112 dBc	-100 dBc
10 Hz	-140 dBc	-125 dBc
100 Hz	-150 dBc	-145 dBc
1 kHz	-157 dBc	-150 dBc
10 kHz	-160 dBc	-155 dBc
100 kHz	-160 dBc	-155 dBc
Aging		
Per day:	<5.0E-11	<3.0E-10
Per year:	<1.5E-8	<4.0E-8
10 years:	<2.0E-7	<1.0E-6
Frequency Retrace (after up to 24 hrs.off and 1 hour on at 25° C):		
	±1.0E-8	±1.0E-8
Acceleration sensitivity		
Per g. total gamma	≤3.0E-9	≤1.5E-9
Low g. option, total gamma	N/A	≤2.0E-10
Frequency change vs. Temperature		
-40° C to +65° C:	±4.0E-9	
Warm-up time from +25° C	<5 minutes to within	
	2.0E-8 of final frequency	
Input Voltage		
Range:	12 to 15 Vdc	
Sensitivity:	<5.0E-10 for ±5% voltage change	
Steady-state power consumption		
at 25° C:	<1.3 W in vacuum	
Warm-up power consumption:	4 to 8 W	
Electronic Frequency Control		
(EFC) Range	±4.0E-7 minimum	
EFC Input	0 to 5 Vdc, (+) sensing	
EFC Linearity	10% typical	
Load change sensitivity:	±1.0E-9 for ±5% load change	

### ENVIRONMENTAL & PHYSICAL SPECIFICATIONS

Operating Temperature:	-40° C to +65° C
Storage temperature:	-55° C to +100° C
Random vibration	
Operating (endurance):	35 g rms
Pyrotechnic shock:	3000 g
Radiation Performance:	
Total Dose:	100 kRad (Si)
ELDRS:	Compliant
SEL:	Compliant
Neutron Fluence:	Contact Factory
Prompt Dose Rate:	Contact Factory
EMI/EMC Performance:	Contact Factory
EEE Parts Screening Level	NASA Grade 2 equivalent
MTBF	>6,000,000 hours
Reliability specification:	MIL-HDBK-217F
Weight:	0.10 kg

## 9600 OUTLINE DRAWING

### PCB-MOUNT PACKAGE STYLE

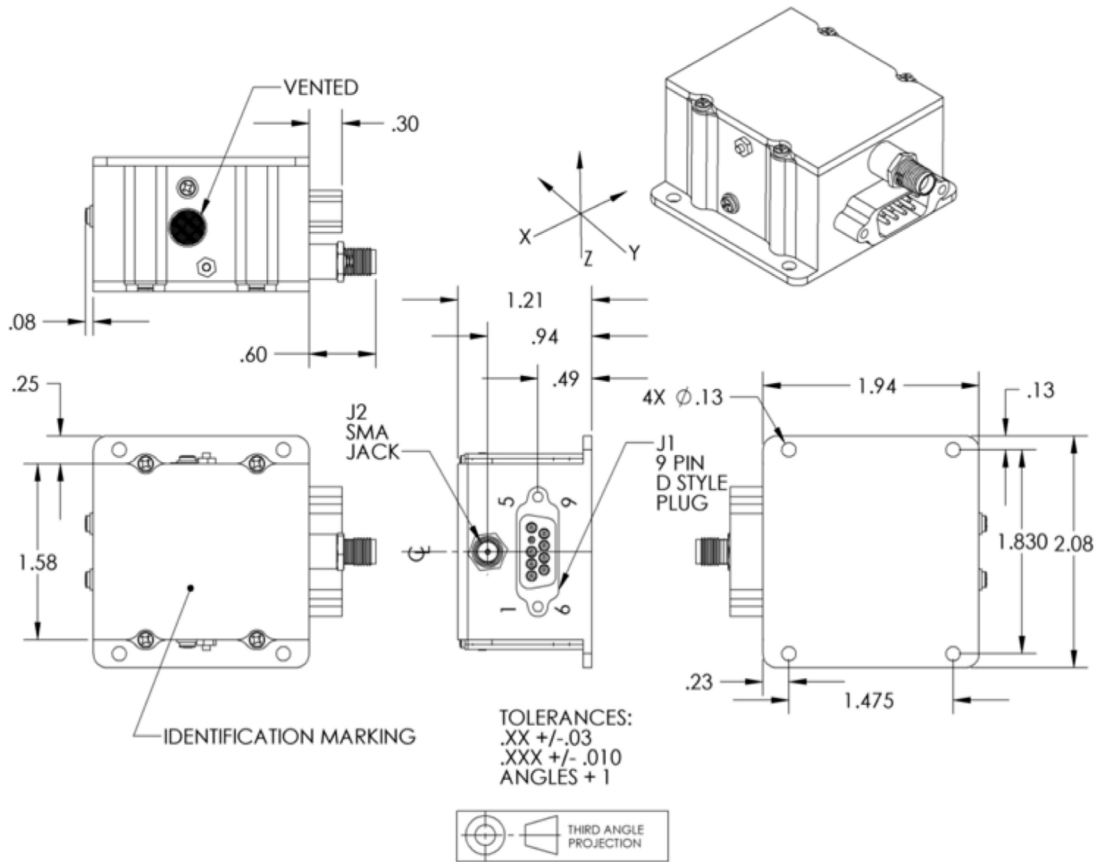


### CONNECTION DESCRIPTIONS

#### PCB-MOUNT PACKAGE STYLE

PIN NO.	FUNCTION
1	RF OUTPUT
2	N/C
3	N/C
4	GROUND/CHASSIS GROUND
5	+12 VDC TO +15 VDC
6	EFC TUNING VOLTAGE INPUT
7	N/C
8	+12VDC TO +15 VDC

**9600 OUTLINE DRAWING**  
**PANEL-MOUNT PACKAGE STYLE**



**CONNECTION DESCRIPTIONS**  
**PANEL-MOUNT PACKAGE STYLE**

PIN NO.	FUNCTION
J1-1	POWER +12 VDC TO +15 VDC
J1-2	N/C
J1-3	N/C
J1-4	GROUND/CHASSIS GROUND
J1-5	EFC TUNING VOLTAGE INPUT
J1-6	GROUND/CHASSIS GROUND
J1-7	POWER +12 VDC TO +15 VDC
J1-8	N/C
J1-9	N/C
J2-1	RF OUTPUT



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